

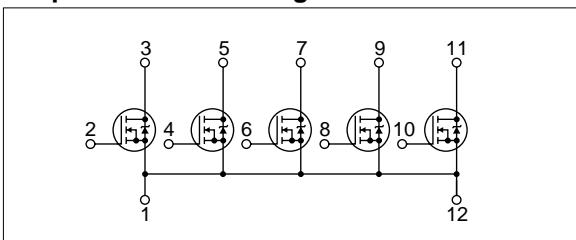
Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings	Unit
V _{DSS}	60	V
V _{GSS}	±20	V
I _D	10	A
I _{D(pulse)}	10 (PW≤1ms, duty≤25%)	A
E _{AS} *	30	mJ
P _T	5 (Ta=25°C, with all circuits operating, without heatsink) 30 (Tc=25°C, with all circuits operating, with infinite heatsink)	W
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ _{j-c}	4.17 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
V _{ISO}	1000 (Between fin and lead pin, AC)	Vrms
T _{ch}	150	°C
T _{stg}	-40 to +150	°C

* : V_{DD}=40V, L=20mH, I_b=1A, unclamped, R_c=50Ω, see Fig. E on page 15.

■ Equivalent circuit diagram



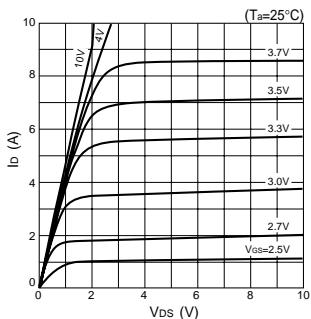
Electrical characteristics

(Ta=25°C)

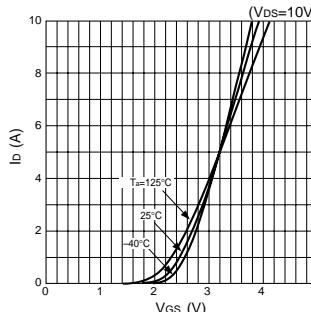
Symbol	Specification			Unit	Conditions
	min	typ	max		
V _{(BR)DSS}	60			V	I _D =100μA, V _{GS} =0V
I _{GS}			±100	nA	V _{GS} =±20V
I _{DS}			100	μA	V _{DS} =60V, V _{GS} =0V
V _{TH}	1.0		2.0	V	V _{DS} =10V, I _D =250μA
R _{e(yfs)}	3.7	5.5		S	V _{DS} =10V, I _D =3A
R _{DS(ON)}		0.16	0.22	Ω	V _{GS} =4V, I _D =3A
C _{iss}		320		pF	V _{DS} =10V,
C _{oss}		160		pF	f=1.0MHz,
C _{rss}		35		pF	V _{GS} =0V
t _{d(on)}		16		ns	I _D =3A, V _{DD} =20V,
t _r		65		ns	R _L =6.67Ω,
t _{d(off)}		70		ns	V _{GS} =5V,
t _f		45		ns	see Fig. 3 on page 16.
V _{SD}		1.05	1.5	V	I _D =5A, V _{GS} =0V
t _{rr}		65		ns	I _D =3A, V _{GS} =0V, di/dt=100A/μs

Characteristic curves

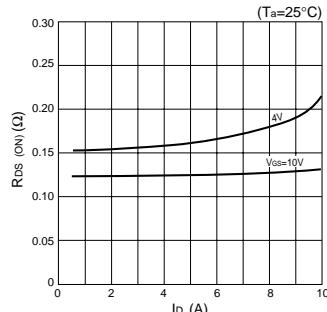
Id-V_{DS} Characteristics (Typical)



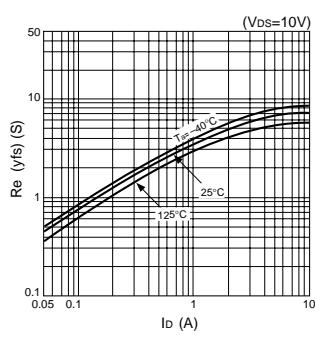
Id-V_{GS} Characteristics (Typical)



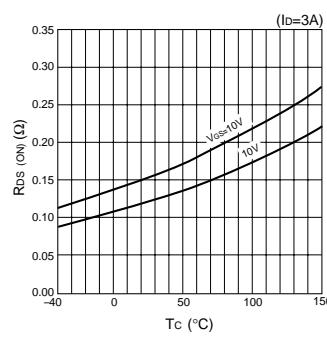
R_{DS(ON)}-Id Characteristics (Typical)



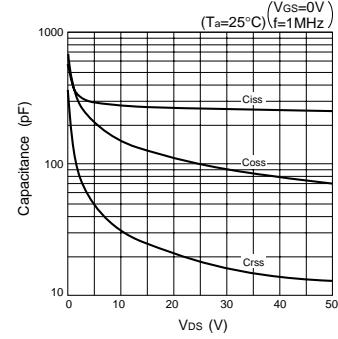
R_{e(yfs)}-Id Characteristics (Typical)



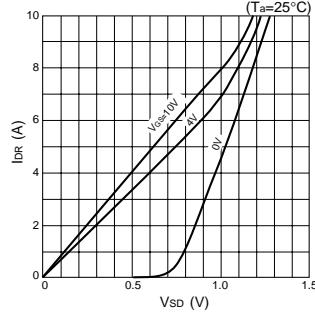
R_{DS(ON)}-Tc Characteristics (Typical)



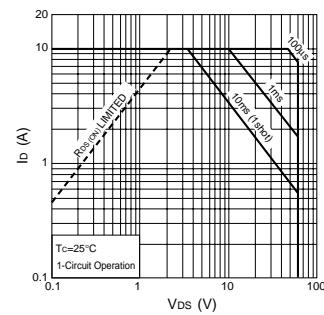
Capacitance-V_{DS} Characteristics (Typical)



I_{DR}-V_{SD} Characteristics (Typical)



Safe Operating Area (SOA)



P_T-T_a Characteristics

